OSRAM LR E67F.01 **Datasheet**







Power TOPLED®

LR E67F.01 - Dual **Binning**

PowerTOPLED, a powerful member of the TOPLED family. Thanks to their high luminous efficacy, the LEDs are ideal for rear light clusters and indicators on vehicles and for display panels for traffic control systems.





Applications

- Functional Illumination

- Static Signaling

Features

- Package: white PLCC-4 package, colorless clear resin
- Chip technology: Thinfilm
- Typ. Radiation: 120° (Lambertian emitter)
- Color: λ_{dom} = 625 nm (• red)
- Corrosion Robustness Class: 3B
- Qualifications: AEC-Q102 Qualified with RV-level 1
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)





Ordering Information

Туре	Luminous Intensity ¹⁾ I _F = 4 mA I _v	Luminous Intensity 1) I _F = 50 mA I _V	Ordering Code
LR E67F.01-S1T2-1-3X5X+7B8C-46-G3R3	180 450 mcd	2240 4500 mcd	Q65113A5551



Maximum Ratings Parameter	Symbol		Values
Operating Temperature	T _{op}	min. max.	-40 °C 100 °C
Storage Temperature	T_{stg}	min. max.	-40 °C 100 °C
Junction Temperature	T _j	max.	125 °C
Junction Temperature for short time applications*	T _i	max.	150 °C
Forward current T _S = 25 °C	I _F	min. max.	3 mA 70 mA
Forward current pulsed D = 0.005 %; T _s = 25 °C	F pulse	max.	100 mA
Reverse voltage ²⁾ T _S = 25 °C	V_R	max.	12 V
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	V_{ESD}		2 kV

^{*} The median lifetime (L70/B50) for Tj = 150°C is 100h.



Characteristics

 I_F = 50 mA; T_S = 25 °C

Parameter	Symbol	Values	
Peak Wavelength	λ_{peak}	min.	634 nm
Dominant Wavelength 3)	λ_{dom}	min.	620 nm
$I_{\rm F} = 50 \text{ mA}$	dom	typ.	625 nm
		max.	630 nm
Viewing angle at 50% $\rm I_{\rm V}$	2φ	typ.	120 °
Forward Voltage 4)	V_{F}	min.	1.90 V
$I_F = 50 \text{ mA}$,	typ.	2.15 V
		max.	2.50 V
Reverse current ²⁾	I _R	typ.	0.01 μΑ
V _R = 12 V	TX	max.	10 µA
Temperature Coefficient of Peak Wavelength -10°C ≤ T ≤ 100°C	$TC_{_{\lambda peak}}$	typ.	0.14 nm / K
Real thermal resistance junction/solderpoint ⁵⁾	R _{thJS real}	typ.	90 K / W
·	ແນວ ເອສ	max.	130 K / W
Electrical thermal resistance junction/solderpoint 5)	R _{thJS elec.}	typ.	47 K / W
with efficiency η _e = 48 %	1100 elec.	max.	68 K / W



Brightness Groups

Group	Luminous Intensity 1) I _F = 4 mA	Luminous Intensity. 1) I _F = 4 mA	Luminous Flux ⁶⁾ I _F = 4 mA
	min.	max.	typ.
	ı _v	I _v	Φ _V
S1	180 mcd	224 mcd	606 mlm
S2	224 mcd	280 mcd	756 mlm
T1	280 mcd	355 mcd	953 mlm
T2	355 mcd	450 mcd	1208 mlm

Brightness Groups

Group	Luminous Intensity 1) I _F = 50 mA	Luminous Intensity. 1) I _F = 50 mA	Luminous Flux ⁶⁾ I _F = 50 mA
	min.	max.	typ.
	l _v	l _v	Φ_{V}
7B	2240 mcd	2500 mcd	7110 mlm
8B	2500 mcd	2800 mcd	7950 mlm
5C	2800 mcd	3150 mcd	8925 mlm
6C	3150 mcd	3550 mcd	10050 mlm
7C	3550 mcd	4000 mcd	11325 mlm
8C	4000 mcd	4500 mcd	12750 mlm



Forward Voltage Groups

Group	Forward Voltage 4)	Forward Voltage 4)	
	$I_F = 4 \text{ mA}$	$I_F = 4 \text{ mA}$	
	min.	max.	
	V_{F}	V_{F}	
3X	1.65 V	1.71 V	
3Y	1.71 V	1.77 V	
4X	1.77 V	1.83 V	
4Y	1.83 V	1.89 V	
5X	1.89 V	1.95 V	

Forward Voltage Groups

Group	Forward Voltage ⁴⁾ I _F = 50 mA min. V _F	Forward Voltage ⁴⁾ I _F = 50 mA max. V _F	
G3	1.90 V	2.05 V	
K3	2.05 V	2.20 V	
N3	2.20 V	2.35 V	
R3	2.35 V	2.50 V	

Wavelength Groups

Group	Dominant Wavelength 3)	Dominant Wavelength 3)	
	I _F = 4 mA	$I_F = 4 \text{ mA}$	
	min.	max.	
	λ_{dom}	$\lambda_{\sf dom}$	
1	619 nm	630 nm	

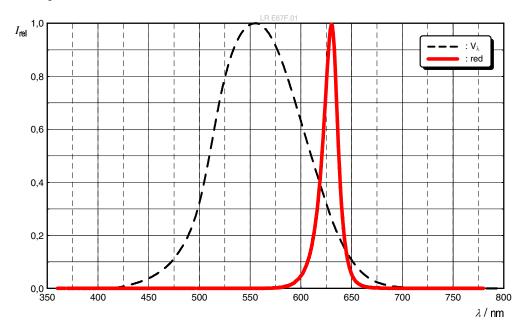
Wavelength Groups

Group	Dominant Wavelength 3)	Dominant Wavelength 3)	
	$I_F = 50 \text{ mA}$	$I_F = 50 \text{ mA}$	
	min.	max.	
	λ_{dom}	$\lambda_{\sf dom}$	
4	620 nm	624 nm	
5	624 nm	627 nm	
6	627 nm	630 nm	



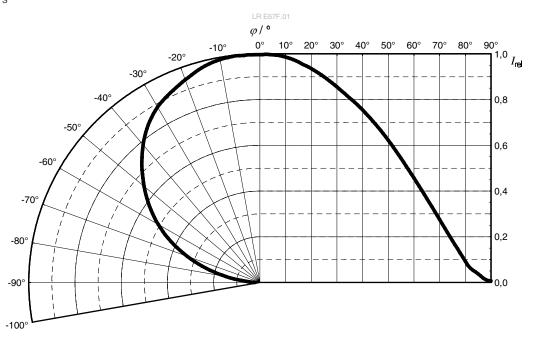
Relative Spectral Emission 6)

$$I_{rel}$$
 = f (λ); I_{F} = 50 mA; T_{S} = 25 °C



Radiation Characteristics 6)

$$I_{rel} = f(\phi); T_S = 25 °C$$

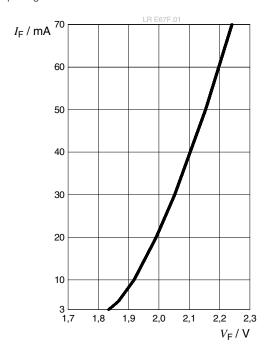




 I_{F} / mA

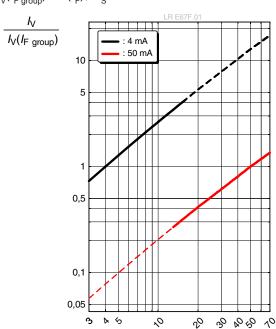
Forward current 6)

$$I_F = f(V_F); T_S = 25 \, ^{\circ}C$$



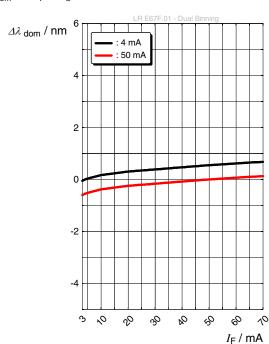
Relative Luminous Intensity 6), 7)

$$I_v/I_v(I_{F \text{ group}}) = f(I_F); T_S = 25 \text{ }^{\circ}\text{C}$$



Dominant Wavelength 6)

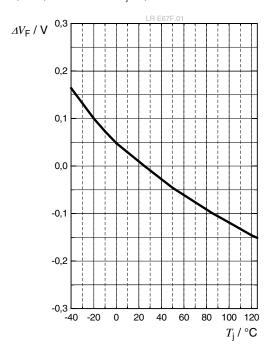
$$\Delta\lambda_{dom} = f(I_F); T_S = 25 \, ^{\circ}C$$





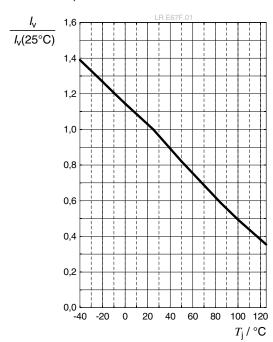
Forward Voltage 6)

$$\Delta V_F = V_F - V_F (25 \ ^{\circ}C) = f(T_j); I_F = 50 \ mA$$



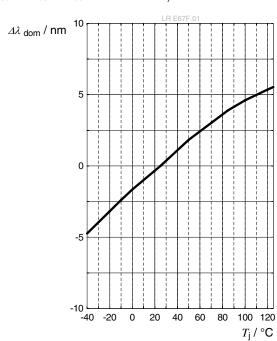
Relative Luminous Intensity 6)

$$I_v/I_v(25 \text{ °C}) = f(T_i); I_F = 50 \text{ mA}$$



Dominant Wavelength 6)

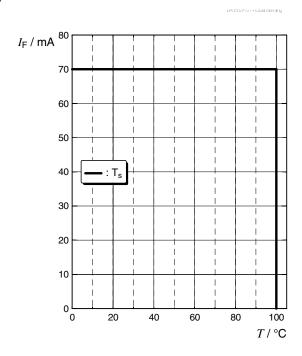
$$\Delta \lambda_{\text{\tiny dom}} = \lambda_{\text{\tiny dom}} - \lambda_{\text{\tiny dom}} (25~^{\circ}\text{C}) = \text{f(T}_{\text{\tiny j}});~\text{I}_{\text{\tiny F}} = 50~\text{mA}$$





Max. Permissible Forward Current 5)

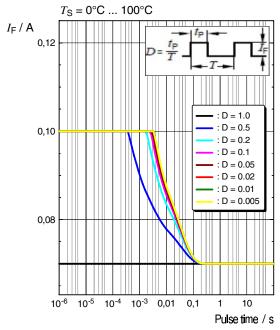
 $I_F = f(T)$



Permissible Pulse Handling Capability

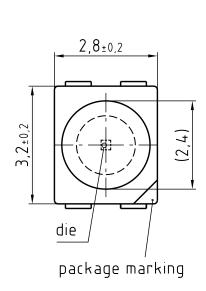
 $I_F = f(t_p)$; D: Duty cycle; $T_S = 25 \, ^{\circ}C$

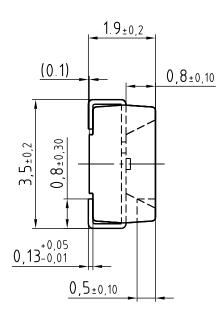
LR E67F.01 - Dual Binning

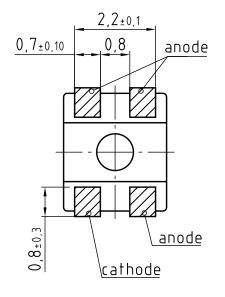




Dimensional Drawing 8)







C63062-A3861-A6..-05

Further Information:

Approximate Weight: 30.0 mg Package marking: Cathode

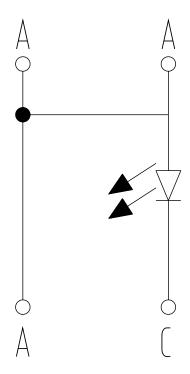
Corrosion test: Class: 3B

Test condition: 40°C / 90 % RH / 15 ppm H₂S / 14 days (stricter than IEC

60068-2-43)

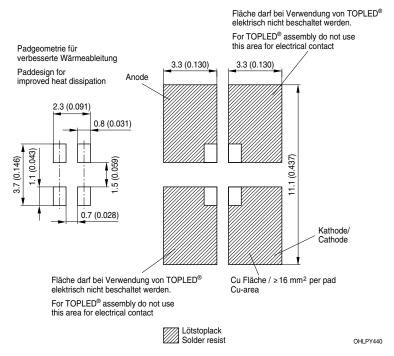


Electrical Internal Circuit





Recommended Solder Pad 8)

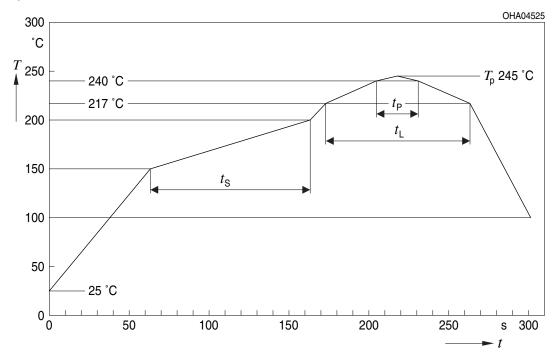


For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for ultra sonic cleaning.



Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



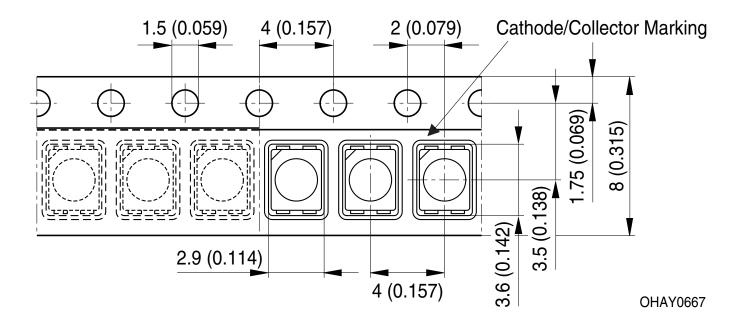
Symbol	Symbol Pb-Free (SnAgCu) Assembly		Unit	
	Minimum	Recommendation	Maximum	
'		2	3	K/s
t _s	60	100	120	S
		2	3	K/s
T_{L}		217		°C
$t_{\scriptscriptstyle \perp}$		80	100	S
T_{P}		245	260	°C
t _P	10	20	30	S
		3	6	K/s
		-	-	
			480	S
	t _s T _L t _L T _P	Minimum t _s 60 T _L t _L T _P	$\begin{array}{c cccc} & Minimum & Recommendation \\ & & 2 \\ \hline t_s & 60 & 100 \\ & & 2 \\ \hline T_L & & 217 \\ t_L & & 80 \\ \hline T_P & & 245 \\ t_P & 10 & 20 \\ \hline \end{array}$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

All temperatures refer to the center of the package, measured on the top of the component

^{*} slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

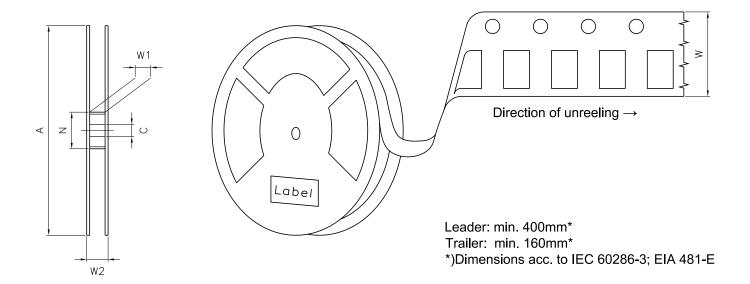


Taping 8)





Tape and Reel 9)

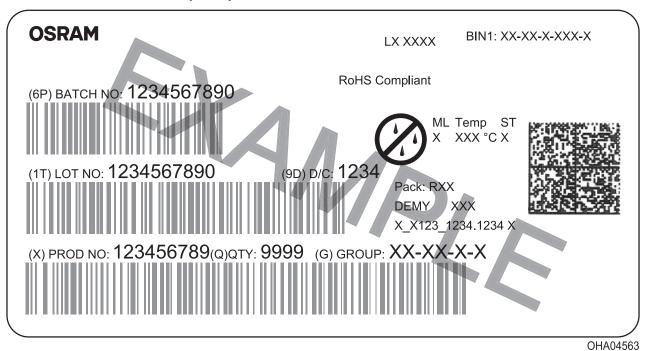


Reel Dimensions

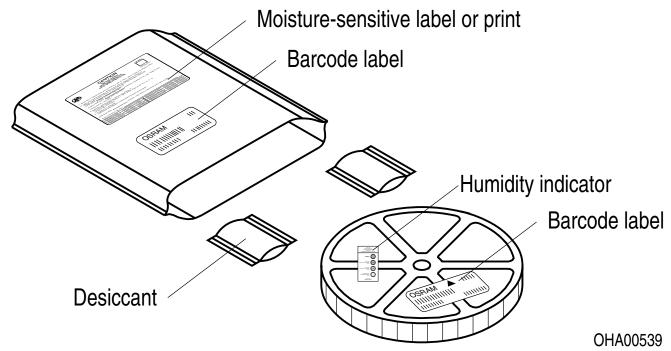
Α	W	N_{\min}	W_1	$W_{2 max}$	Pieces per PU
180 mm	8 + 0.3 / - 0.1 mm	60 mm	8.4 + 2 mm	14.4 mm	2000



Barcode-Product-Label (BPL)



Dry Packing Process and Materials 8)



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet fall into the class exempt group (exposure time 10000 s). Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit https://ams-osram.com/support/application-notes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.



Glossary

- Brightness: Brightness values are measured during a current pulse of typically 25 ms, with an internal reproducibility of ±8 % and an expanded uncertainty of ±11 % (acc. to GUM with a coverage factor of k = 3).
- Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- Wavelength: The wavelength is measured at a current pulse of typically 25 ms, with an internal reproducibility of ±0.5 nm and an expanded uncertainty of ±1 nm (acc. to GUM with a coverage factor of k =
- Forward Voltage: The forward voltage is measured during a current pulse of typically 8 ms, with an internal reproducibility of ±0.05 V and an expanded uncertainty of ±0.1 V (acc. to GUM with a coverage factor of k = 3).
- 5) Thermal Resistance: Rth max is based on statistic values (6 σ) used for Derating.
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- Characteristic curve: In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- 9) Tape and Reel: All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.



Revision History

Version	Date	Change
1.0	2024-06-07	Initial Version
1.1	2024-09-03	Features
1.2	2024-11-22	Dimensional Drawing
1.3	2024-12-11	Maximum Ratings



EU RoHS and China RoHS compliant product 此产品符合欧盟 RoHS 指令的要求; 按照中国的相关法规和标准, 不含有毒有害物质或元素。

Published by ams-OSRAM AG

Tobelbader Strasse 30, 8141 Premstaetten, Austria Phone +43 3136 500-0 ams-osram.com © All rights reserved





Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ams OSRAM:

LR E67F.01-S1T2-1-3X5X+7B8C-46-G3R3-S